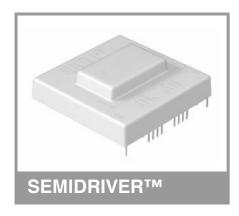
# SKHI 21A R



# Hybrid Dual MOSFET Driver

Order Number L5071603

## SKHI 21A R

#### Features\*

- Drives MOSFET with V<sub>DS(on)</sub> < 10 V</li>
- · Two output channels
- CMOS compatible inputs
- Short circuit protection by V<sub>DS</sub> monitoring and switch off
- · Drive interlock top / bottom
- · Insulation by transformers
- Under voltage protection
- Error latch / output
- · RoHS compliant

# Typical Applications

Driver for MOSFET modules in bridge circuits in industrial applications

### **Footnotes**

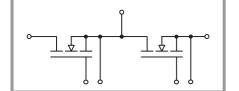
1) See Technical Explanation chapter "Electrical Characteristics"

 $^{2)}$  Typ. 5V at  $R_{DS}$  = 18  $k\Omega$  ,  $C_{DS}$  = 330 pF

| Absolute Maximum Ratings |  |          |       |  |  |  |  |  |
|--------------------------|--|----------|-------|--|--|--|--|--|
| Symbol                   | Conditions   | Values   | Unit  |  |  |  |  |  |
|                          |  |          |       |  |  |  |  |  |
| Vs                       | Supply voltage primary                                     | 18       | V     |  |  |  |  |  |
| $V_{iH}$                 | Input signal voltage (HIGH)                                | Vs + 0.3 | V     |  |  |  |  |  |
| I <sub>outPEAK</sub>     | Output peak current  | 20       | Α     |  |  |  |  |  |
| I <sub>outAVmax</sub>    | Output average current                                     | 40       | mA    |  |  |  |  |  |
| f <sub>max</sub>         | Max. switching frequency                                   | 50       | kHz   |  |  |  |  |  |
| V <sub>DS</sub>          | Drain-source voltage senses across the MOSFET              | 1700     | V     |  |  |  |  |  |
| dv/dt                    | Rate of rise and fall of voltage secondary to primary side | 50       | kV/μs |  |  |  |  |  |
| V <sub>isol IO</sub>     | Insulation test voltage input - output (AC, rms, 2s)       | 4000     | V     |  |  |  |  |  |
| V <sub>isol12</sub>      | Insulation test voltage output 1 - output 2 (AC, rms, 2s)  | 1500     | V     |  |  |  |  |  |
| R <sub>Gon min</sub>     | Minimum rating for external R <sub>Gon</sub>               | 3        | Ω     |  |  |  |  |  |
| R <sub>Goff min</sub>    | Minimum rating for external R <sub>Goff</sub>              | 3        | Ω     |  |  |  |  |  |
| Q <sub>out/pulse</sub>   | Max. rating for output charge per pulse1)                  | 4        | μС    |  |  |  |  |  |
| T <sub>op</sub>          | Operating temperature                                      | -40 85   | °C    |  |  |  |  |  |
| T <sub>stg</sub>         | Storage temperature  | -40 85   | °C    |  |  |  |  |  |

| Characteristics       |   |      |      |      |                   |  |  |
|-----------------------|---|------|------|------|-------------------|--|--|
| Symbol                | Conditions  | min. | typ. | max. | Unit              |  |  |
|                       |   |      |      |      |                   |  |  |
| Vs                    | Supply voltage primary side                                     | 14.4 | 15   | 15.6 | V                 |  |  |
| I <sub>S0</sub>       | Supply current primary (no load)                                |      | 80   |      | mA                |  |  |
|                       | Supply current primary side (max.)                              |      |      | 290  | mA                |  |  |
| Vi                    | Input signal voltage on / off                                   |      | 15/0 |      | V                 |  |  |
| $V_{IT+}$             | Input threshold voltage (HIGH)                                  |      |      | 12.5 | V                 |  |  |
| V <sub>IT-</sub>      | Input threshold voltage (LOW)                                   | 4.5  |      |      | V                 |  |  |
| R <sub>IN</sub>       | Input resistance  |      | 10   |      | kΩ                |  |  |
| V <sub>G(on)</sub>    | Turn on output voltage  |      | 15   |      | V                 |  |  |
| $V_{G(off)}$          | Turn off output voltage   |      | 0    |      | V                 |  |  |
| R <sub>GS</sub>       | Internal gate-source resistance                                 |      | 22   |      | kΩ                |  |  |
| f <sub>ASIC</sub>     | Asic system switching frequency                                 |      | 8    |      | MHz               |  |  |
| t <sub>d(on)IO</sub>  | Input-output turn-on propagation time                           | 0.85 | 1    | 1.15 | μs                |  |  |
| t <sub>d(off)IO</sub> | Input-output turn-off propagation time                          | 0.85 | 1    | 1.15 | μs                |  |  |
| t <sub>d(err)</sub>   | Error input-output propagation time                             |      | 0.6  |      | μs                |  |  |
| tperreset             | Error reset time  |      | 9    |      | μs                |  |  |
| t <sub>TD</sub>       | Top-Bot interlock dead time                                     |      | 4.3  |      | μs                |  |  |
| V <sub>DS(ref)</sub>  | Reference voltage for V <sub>DS</sub> -monitoring <sup>2)</sup> |      | 5    | 10   | V                 |  |  |
| C <sub>ps</sub>       | Coupling capacitance prim sec                                   |      | 12   |      | pF                |  |  |
| W                     | weight  |      | 45   |      | g                 |  |  |
| MTBF                  | Mean Time Between Failure T <sub>a</sub> = 40°C                 |      | 2    |      | 10 <sup>6</sup> h |  |  |

This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

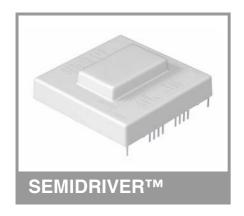


**Driver Core** 

### \*IMPORTANT INFORMATION AND WARNINGS

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